

**BCY58, VII, VIII, IX, X  
BCY59, VII, VIII, IX, X**

**SILICON  
NPN TRANSISTORS**



[www.centralsemi.com](http://www.centralsemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR BCY58 and BCY59 series types are silicon NPN epitaxial planar transistors, mounted in a hermetically sealed metal case, designed for low noise amplifier and switching applications.



**TO-18 CASE**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

	<b>SYMBOL</b>	<b>BCY58</b>	<b>BCY59</b>	<b>UNITS</b>
Collector-Base Voltage	$V_{CBO}$	32	45	V
Collector-Emitter Voltage	$V_{CEO}$	32	45	V
Emitter-Base Voltage	$V_{EBO}$	7.0	7.0	V
Continuous Collector Current	$I_C$	100	100	mA
Peak Collector Current	$I_{CM}$	200	200	mA
Peak Base Current	$I_{BM}$	200	200	mA
Power Dissipation	$P_D$	340	340	mW
Power Dissipation ( $T_C=25^\circ\text{C}$ )	$P_D$	1.0	1.0	W
Operating and Storage Junction Temperature	$T_J, T_{stg}$	-65 to +200	-65 to +200	$^\circ\text{C}$
Thermal Resistance	$\Theta_{JA}$	450	450	$^\circ\text{C}/\text{W}$
Thermal Resistance	$\Theta_{JC}$	150	150	$^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>			<b>MAX</b>			<b>UNITS</b>
		<b>BCY58-VII</b>	<b>BCY58-VIII</b>	<b>BCY58-IX</b>	<b>BCY58-X</b>	<b>BCY59-VII</b>	<b>BCY59-VIII</b>	<b>BCY59-IX</b>
$I_{CBO}$	$V_{CB}=\text{Rated } V_{CBO}$			10				nA
$I_{CBO}$	$V_{CB}=\text{Rated } V_{CBO}, T_A=150^\circ\text{C}$			10				$\mu\text{A}$
$I_{EBO}$	$V_{EB}=5.0\text{V}$			10				nA
$BV_{CBO}$	$I_C=10\mu\text{A}$ (BCY58)	32						V
$BV_{CBO}$	$I_C=10\mu\text{A}$ (BCY59)	45						V
$BV_{CEO}$	$I_C=2.0\text{mA}$ (BCY58)	32						V
$BV_{CEO}$	$I_C=2.0\text{mA}$ (BCY59)	45						V
$BV_{EBO}$	$I_E=1.0\mu\text{A}$	7.0						V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=250\mu\text{A}$			0.35				V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=2.5\text{mA}$			0.70				V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=250\mu\text{A}$	0.60		0.85				V
$V_{BE(SAT)}$	$I_C=100\text{mA}, I_B=2.5\text{mA}$	0.75		1.20				V

	$V_{CE}=5.0\text{V}, I_C=10\mu\text{A}$	<b>BCY58-VII</b>			<b>BCY58-VIII</b>			<b>BCY58-IX</b>			<b>BCY58-X</b>		
		<b>MIN</b>	<b>Typ</b>	<b>MAX</b>	<b>MIN</b>	<b>MAX</b>	<b>MIN</b>	<b>MAX</b>	<b>MIN</b>	<b>MAX</b>	<b>MIN</b>	<b>MAX</b>	
$h_{FE}$	$V_{CE}=5.0\text{V}, I_C=10\mu\text{A}$	-	20	-	20	-	40	-	100	-			
$h_{FE}$	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$	120	-	220	180	310	250	460	380	630			
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	80	-	-	120	400	160	630	240	1000			
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=100\text{mA}$	40	-	-	45	-	60	-	60	-			

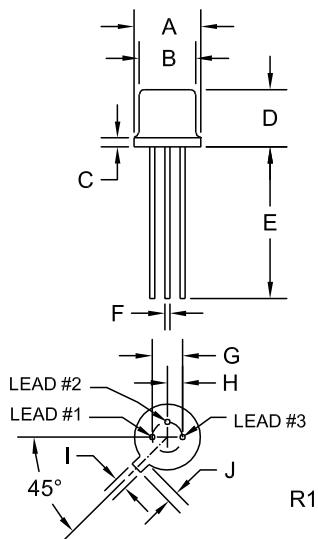
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**ELECTRICAL CHARACTERISTICS - Continued: ( $T_A=25^\circ C$  unless otherwise noted)**

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$f_T$	$V_{CE}=5.0V$ , $I_C=10mA$ , $f=100MHz$	150			MHz
$C_{ob}$	$V_{CB}=10V$ , $I_E=0$ , $f=1.0MHz$			5.0	pF
$C_{ib}$	$V_{EB}=0.5V$ , $I_C=0$ , $f=1.0MHz$			15	pF
NF	$V_{CE}=5.0V$ , $I_C=0.2mA$ , $R_S=2.0k\Omega$ , $f=1.0kHz$ , $B=200Hz$			10	dB
$t_{on}$	$V_{CC}=10V$ , $I_C=10mA$ , $I_{B1}=I_{B2}=1.0mA$		85	150	ns
$t_d$	$V_{CC}=10V$ , $I_C=10mA$ , $I_{B1}=I_{B2}=1.0mA$		35		ns
$t_r$	$V_{CC}=10V$ , $I_C=10mA$ , $I_{B1}=I_{B2}=1.0mA$		50		ns
$t_{off}$	$V_{CC}=10V$ , $I_C=10mA$ , $I_{B1}=I_{B2}=1.0mA$		450	800	ns
$t_s$	$V_{CC}=10V$ , $I_C=10mA$ , $I_{B1}=I_{B2}=1.0mA$		400		ns
$t_f$	$V_{CC}=10V$ , $I_C=10mA$ , $I_{B1}=I_{B2}=1.0mA$		80		ns
$t_{on}$	$V_{CC}=10V$ , $I_C=100mA$ , $I_{B1}=I_{B2}=10mA$		55	150	ns
$t_d$	$V_{CC}=10V$ , $I_C=100mA$ , $I_{B1}=I_{B2}=10mA$		5.0		ns
$t_r$	$V_{CC}=10V$ , $I_C=100mA$ , $I_{B1}=I_{B2}=10mA$		50		ns
$t_{off}$	$V_{CC}=10V$ , $I_C=100mA$ , $I_{B1}=I_{B2}=10mA$		450	800	ns
$t_s$	$V_{CC}=10V$ , $I_C=100mA$ , $I_{B1}=I_{B2}=10mA$		250		ns
$t_f$	$V_{CC}=10V$ , $I_C=100mA$ , $I_{B1}=I_{B2}=10mA$		20		ns

**TO-18 CASE - MECHANICAL OUTLINE**



SYMBOL	DIMENSIONS			
	INCHES	MILLIMETERS	MIN	MAX
A (DIA)	0.209	0.230	5.31	5.84
B (DIA)	0.178	0.195	4.52	4.95
C	-	0.030	-	0.76
D	0.170	0.210	4.32	5.33
E	0.500	-	12.70	-
F (DIA)	0.016	0.019	0.41	0.48
G (DIA)	0.100		2.54	
H	0.050		1.27	
I	0.036	0.046	0.91	1.17
J	0.028	0.048	0.71	1.22

TO-18 (REV: R1)

**LEAD CODE:**

- 1) Emitter
- 2) Base
- 3) Collector

**MARKING:**  
**FULL PART NUMBER**

R2 (8-November 2013)

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- Package details
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- Custom product and package development

### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

### CONTACT US

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